

2.4~2.5 GHz High Power Amplifier

RFIC Preliminary 2018.01 Rev3.0

DESCRIPTION

The AP1076 is a 2.4~ 2.5 GHz linear power amplifier MMIC (Microwave Monolithic Integrated Circuit) fabricated with InGaP HBT process. Input match and a power detector are incorporated on-chip for ease of use, while external output match is used to provide the flexibility the users with the flexibility in system optimization. The device is intended for use in WLAN IEEE802.11b/g/n/ac applications. It also serves as a general purpose PA solution for ISM band wireless systems requiring high power and/or high linearity.

The AP1076 is provided in a 3x3 mm, 16 pin QFN (Quad Flat No-leads) package.

KEY FEATURES

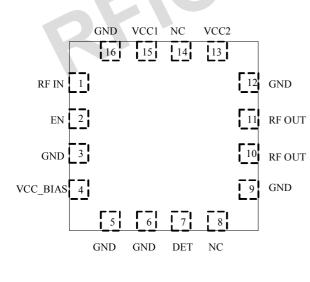
- **5V Condition Performance**
- Quiescent Current
 270mA
- High Linearity:
 26dBm @ EVM = 3 %, with 64QAM OFDM
- High PAE:
- 17% @ 26dBm
- High Gain:
 - 32dB Power Gain

Pin Details • On Chip Detector

Major Applications

- IEEE 802.11b/g/n
- IEEE 802.11ac 256QAM
- 2.4 GHz ISM Band Application
- Suitable for high power WLAN applications
- High power WLAN AP Router applications
- Portable/ Embedded RF module

Pin Assignment



Pin Number	Name	Description			
1	RF IN	RF input.			
2	EN	Power Amplifier Enable			
3	GND	Ground.			
4	VCC_BIAS	Supply voltage for bias circuit.			
5	GND	Ground.			
6	GND	Ground.			
7	DET	Detector output voltage.			
8	NC	No connection			
9	GND	Ground.			
10	RF OUT	RF output			
11	RF OUT	RF output			
12	GND	Ground.			
13	VCC2	PA 2 nd stage supply voltage.			
14	NC	No connection			
15	VCC1	PA 1 st stage supply voltage.			
16	GND	Ground.			
Pkg Base	Center Metal	The package ground provides circuit ground as well as heat dissipation path for the power amplifier.			

QFN-16pin, 3x3 (mm)

For more information, please contact us at: Sales Dept.

Sales Dept.

Tel: +886-2-2698-1022

© 2006 RFIC Technology Corporation All rights reserved.





2.4~2.5 GHz High Power Amplifier

~ ...

RFIC Preliminary 2018.01 Rev3.0

Electrical Characteristics

~ .

(VCC = 5V, Vref = 1.8V, TA = 25°C as Measured on the Specification							
Parameter	Min	Тур.	Max	Units	Notes		
Frequency	2.4		2.5	GHz			
Input return loss	15		20	dB	S11		
Output return loss	10		15	dB	S22		
OP1dB		33		dBm	CW signal		
Power Gain	30	32	34	dB			
Linear Power	23 26 28 27	23.5 18 29 28	24 27	dBm	MCS8, HT40, 1.8% EVM MCS8, HT40, 1.25% EVM MCS7, HT20, 3% EVM MCS0, HT20, mask MCS0, HT40, mask		
Harmonics	-55 -50	-50 -47	-42 -42	dBm/ MHz	2fo @ 29dBm, CCK signal, BT = 0.045 3fo @ 29dBm, CCK signal, BT = 0.045		
Iref		1		mA	@ Idle current		
Idle current	260	5	280	mA			
Current Consumption	360 300 450		400 360 510	mA	 @ 23.5 dBm, MCS8, HT40, 1.8% EVM @ 18 dBm, MCS8, HT40, 1.25% EVM @ 26 dBm, MCS7, HT20, 3% EVM 		
Gain flatness		1		dB	100MHz bandwidth		
PAE	11.2 15.6		12.4 17.7	%	@ 23.5 dBm, MCS8, HT40, 1.8% EVM @ 26 dBm, MCS7, HT20, 3% EVM		
Detector output		1.5		V	@ 26dBm, OFDM signal, MCS7, HT20 mode		

Note 1: Performance is guaranteed only under the conditions listed in this Table.

RFIC Technology Corp. reserved the right to make any changes to the specifications without notice.

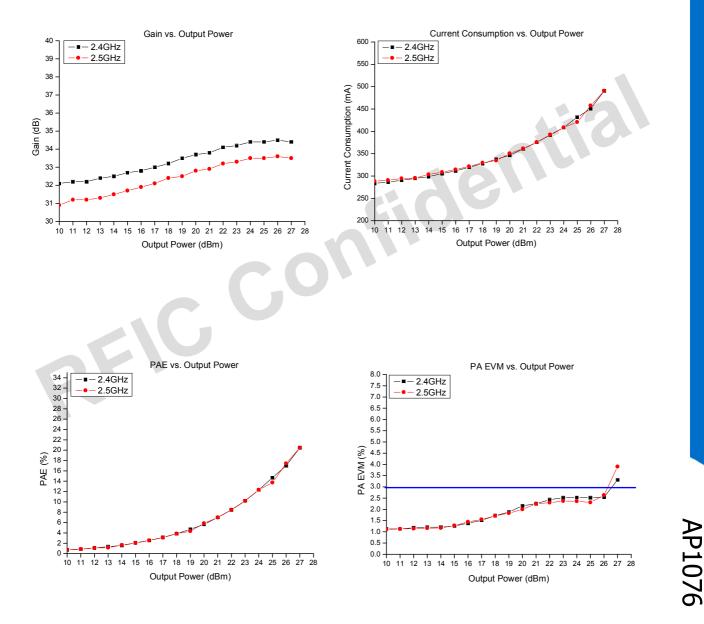
© 2006 RFIC Technology Corporation All rights reserved.



2.4~2.5 GHz High Power Amplifier

RFIC Preliminary 2018.01 Rev3.0

Electrical Characteristics Charts Vcc = 5V



For more information, please contact us at: Sales Dept.

e-mail: sales@rfintc.com

RFIC Technology Corp. reserved the right to make any changes to the specifications without notice.

© 2006 RFIC Technology Corporation All rights reserved.

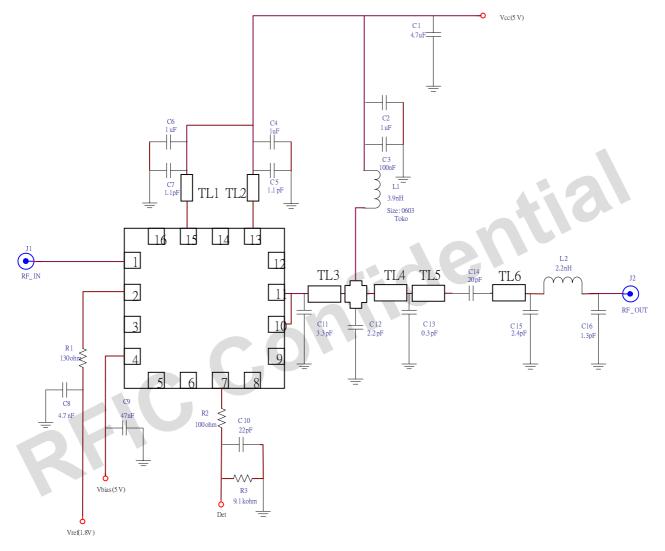




2.4~2.5 GHz High Power Amplifier

RFIC Preliminary 2018.01 Rev3.0

AP1076 Evaluation Board Schematic Diagram for 5V Application



Transmission Line (50 Ω)	Physical Length (mm)	Length Measurement		
TL1	0.78	IC edge to C7 center		
TL2	0.78	IC edge to C5 center		
TL3	1.35	C11 center to C12 center		
TL4	1.76	C12 center to C13 center		
TL5	0.86	C13 center to C14 center		
TL6	0.8	C14 center to C15 center		

For more information, please contact us at:

© 2006 RFIC Technology Corporation All rights reserved.

Sales Dept.

Tel: +886-2-2698-1022

e-mail: sales@rfintc.com RFIC Technology Corp. reserved the right to make any changes to the specifications without notice.



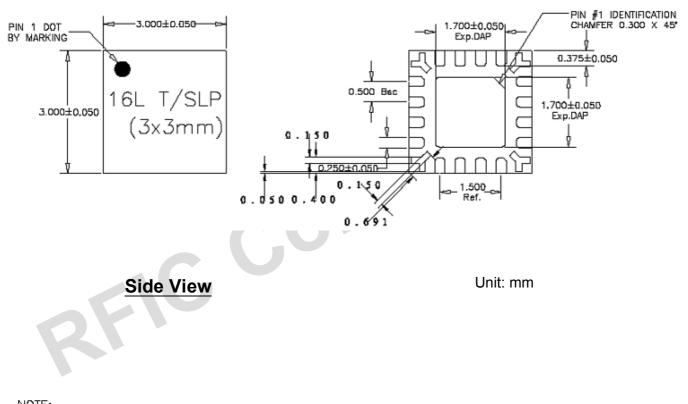
2.4~2.5 GHz High Power Amplifier

RFIC Preliminary 2018.01 Rev3.0

Package Outline

Top View

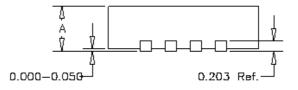
Bottom View



NOTE:

1) TSLP AND SLP SHARE THE SAME EXPOSE OUTLINE BUT WITH DIFFERENT THICKNESS:

		TSLP	ŚLP
	MAX.	0.800	0.900
I A I	NOM.	0.750	0.850
	MIN.	0.700	0.800



© 2006 RFIC Technology Corporation All rights reserved.

For more information,please contact us at: Sales Dept. Tel: +886-2-2698-1022

e-mail: sales@rfintc.com RFIC Technology Corp. reserved the right to make any changes to the specifications without notice.





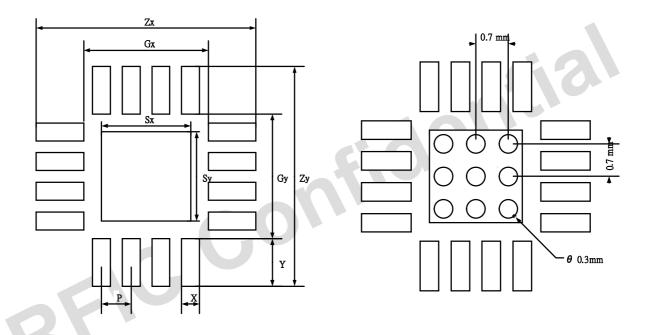
2.4~2.5 GHz High Power Amplifier

RFIC Preliminary 2018.01 Rev3.0

Suggested PCB Layout

Thermal PAD Via Design

I/O Pin, Central PAD Layout



PCB Footprint Dimension (mm)								
Р	X	Y	Sx	Sy	Gx	Gy	Zx	Zy
0.5	0.3	0.85	1.5	1.5	2.1	2.1	3.8	3.8

AP1076

© 2006 RFIC Technology Corporation All rights reserved.

Sales Dept. Tel: +886-2-2698-1022

For more information, please contact us at:

e-mail: sales@rfintc.com

RFIC Technology Corp. reserved the right to make any changes to the specifications without notice.



2.4~2.5 GHz High Power Amplifier

RFIC Preliminary 2018.01 Rev3.0

The product is designed and manufactured for consumer application only and is not intended for any application listed below which requires especially high reliability for the prevention of such defect which could lead to personal injury, death, physical or environmental damage.

- Aircraft equipment.
- Aerospace equipment.
- Undersea equipment.
- Medical equipment.
- Life-saving or life-sustaining applications
- Transportation equipment (vehicles, trains, ships, etc.).
- Traffic signal equipment.
- Disaster prevention / crime prevention equipment.
- Application of similar complexity and/ or reliability requirements to the applications listed in the above.